FAIRCHILD

SEMICONDUCTOR

74F30 8-Input NAND Gate

General Description

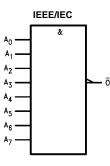
This device contains a single gate, which performs the logic NAND function.

Ordering Code:

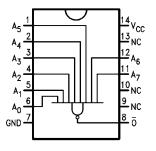
Order Number	Package Number	Package Description
74F30SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F30SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F30PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Din Namos	Description	U.L.	Input I _{IH} /I _{IL}		
Fin Names	Description	HIGH/LOW	Output I _{OH} /I _{OL}		
A ₀ -A ₇	Inputs	1.0/1.0	20 µA/–0.6 mA		
ō	Output	50/33.3	–1 mA/20 mA		

Function Table

Inputs								Output
A ₀	A ₁	A ₂	A_3	A_4	A ₅	A ₆	A ₇	o
L	Х	Х	Х	Х	Х	Х	Х	Н
Х	L	Х	Х	Х	Х	Х	Х	н
Х	Х	L	Х	Х	Х	Х	Х	н
Х	Х	Х	L	Х	Х	Х	Х	н
Х	Х	Х	Х	L	Х	Х	Х	н
Х	Х	Х	Х	Х	L	Х	Х	н
х	Х	Х	Х	Х	Х	L	Х	н
х	Х	Х	Х	Х	Х	Х	L	н
н	н	н	н	н	н	н	н	L

L = LOW Voltage Level

X = Immaterial



74F30

Absolute Maximum Ratings(Note 1)

Storage Temperature	$-65^{\circ}C$ to $+150^{\circ}C$
Ambient Temperature under Bias	$-55^{\circ}C$ to $+125^{\circ}C$
Junction Temperature under Bias	-55°C to +150C
V _{CC} Pin Potential to Ground Pin	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to +7.0V
Input Current (Note 2)	-30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with $V_{CC} = 0V$)	
Standard Output	-0.5V to V _{CC}
3-STATE Output	-0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated $I_{OL}\ (mA)$

> -0.5V to V_{CC} -0.5V to +5.5V

Recommended Operating Conditions

Free Air Ambient	Temperature
Supply Voltage	

 $0^{\circ}C$ to $+70^{\circ}C$ +4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

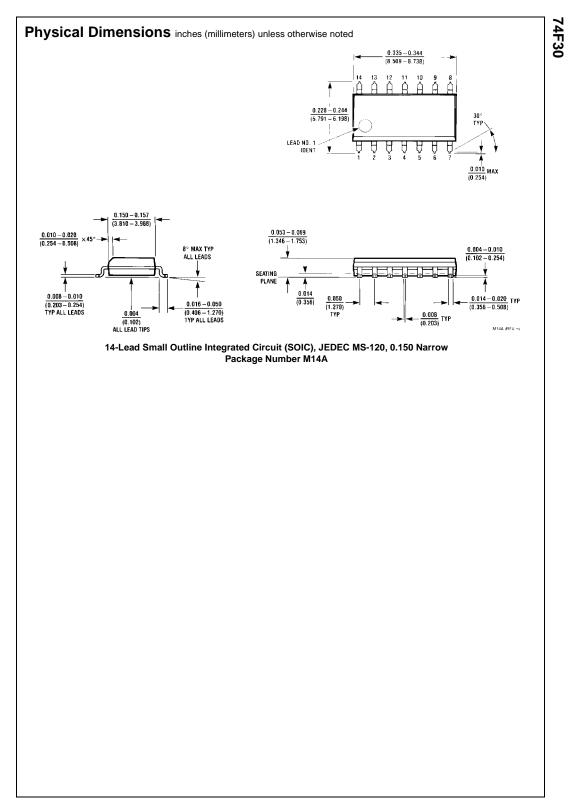
Note 2: Either voltage limit or current limit is sufficient to protect inputs.

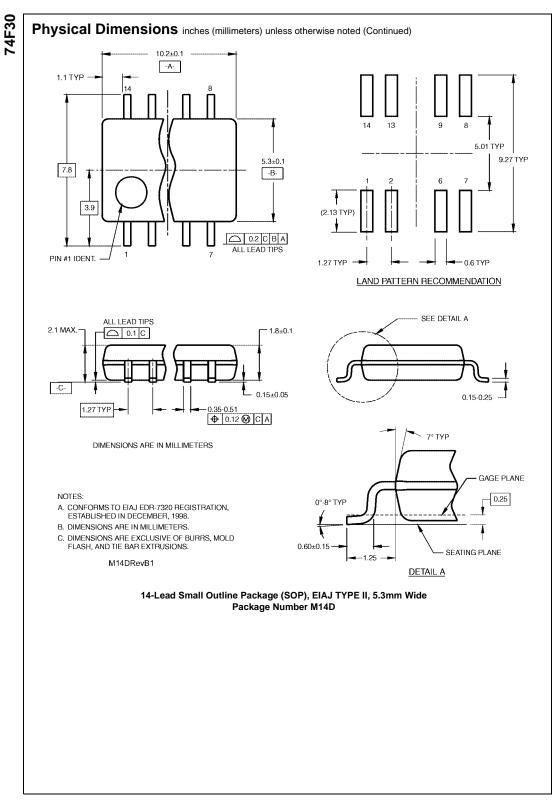
DC Electrical Characteristics

Symbol	Parameter		Min	Тур	Max	Units	Vcc	Conditions	
VIH	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal	
VIL	Input LOW Voltage				0.8	V		Recognized as a LOW Signal	
V _{CD}	Input Clamp Diode Voltage				-1.2	V	Min	I _{IN} = -18 mA	
V _{OH}	Output HIGH	10% V _{CC}	2.5			V	Min	I _{OH} = -1 mA	
	Voltage	5% V _{CC}	2.7			v	IVIIN	$I_{OH} = -1 \text{ mA}$	
V _{OL}	Output LOW	100/ \/			0.5	V	Min	I _{OL} = 20 mA	
	Voltage	10% V _{CC}			0.5				
I _{IH}	Input HIGH				5.0	۸	Max	V _{IN} = 2.7V	
	Current				5.0	μA	wax	$v_{\rm IN} = 2.7 v$	
I _{BVI}	Input HIGH Current				7.0	μA	Max	V _{IN} = 7.0V	
	Breakdown Test				7.0	μΑ	IVIAX	v _{IN} = 7.0 v	
I _{CEX}	Output HIGH				50	μA	Max	V _{OUT} = V _{CC}	
	Leakage Current								
V _{ID}	Input Leakage		4.75			V	0.0	I _{ID} = 1.9 μA	
	Test							All Other Pins Grounded	
I _{OD}	Output Leakage				3.75	μA	0.0	$V_{IOD} = 150 \text{ mV}$	
	Circuit Current				5.75	μΑ	0.0	All Other Pins Grounded	
I _{IL}	Input LOW Current				-0.6	mA	Max	$V_{IN} = 0.5V$	
I _{OS}	Output Short-Circuit Current		-60		-150	mA	Max	$V_{OUT} = 0V$	
I _{CCH}	Power Supply Current			0.5	1.5	mA	Max	V _O = HIGH	
I _{CCL}	Power Supply Current				4.5	mA	Max	$V_0 = LOW$	

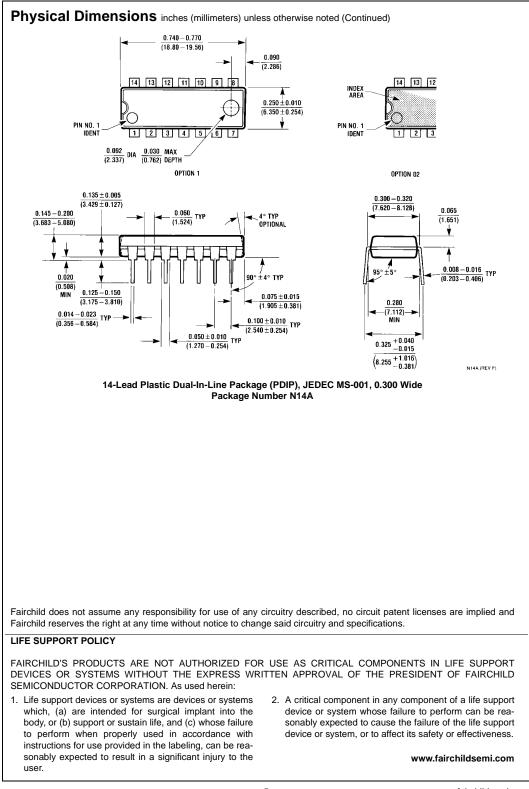
AC Electrical Characteristics

Symbol	Parameter	$T_{A} = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$			$T_{A} = 0^{\circ}C \text{ to } +70^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$		Units	
		Min	Тур	Max	Min	Max		
t _{PLH}	Propagation Delay	1.0	3.7	5.0	1.0	5.5	ns	
t _{PHL}	A_n to \overline{O}	1.5	2.8	5.0	1.5	5.5	115	





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